SGS-THOMSON MICROELECTRONICS

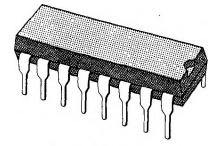
ULN2001A-ULN2003A
ULN2002A-ULN2004A

SEVEN DARLINGTON ARRAYS

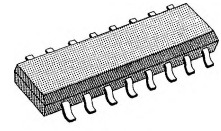
- SEVEN DARLINGTONS PER PACKAGE
- OUTPUT CURRENT 500 mA PER DRIVER (600 mA PEAK)
- OUTPUT VOLTAGE 50 V
- INTEGRAL SUPPRESSION DIODES FOR INDUCTIVE LOADS
- OUTPUTS CAN BE PARALLELED FOR HIGHER CURRENT
- TTL/CMOS/PMOS/DTL COMPATIBLE INPUTS
- INPUTS PINNED OPPOSITE OUTPUTS TO SIMPLIFY LAYOUT

These versatile devices are useful for driving a wide range of loads including solenoids, relays DC motors, LED displays filament lamps, thermal printheads and high power buffers.

The ULN2001A/2002A/2003A and 2004A are supplied in 16 pin plastic DIP packages with a copper leadframe to reduce thermal resistance. They are available also in smali outline package (SO-16) as ULN2001D/2002D/2003D/2004D.



DIP-16 Plastic
(0.25)



SO-16J

ORDER CODES :
ULN2001A/2A/3A/4A (DIP-16)
ULN2001D/2D/3D/4D (SO-16)

DESCRIPTION

The ULN2001A, ULN2002A, ULN2003 and ULN2004A are high voltage, high current darlington arrays each containing seven open collector darlington pairs with common emitters. Each channel is rated at 500 mA and can withstand peak currents of 600 mA. Suppression diodes are included for inductive load driving and the inputs are pinned opposite the outputs to simplify board layout.

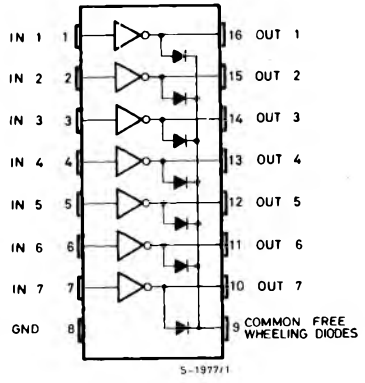
The four versions interface to all common logic families :

ULN2001A	General Purpose, DTL, TTL, PMOS, CMOS
ULN2002A	14-25 V PMOS
ULN2003A	5 V TTL, CMOS
ULN2004A	6–15 V CMOS, PMOS

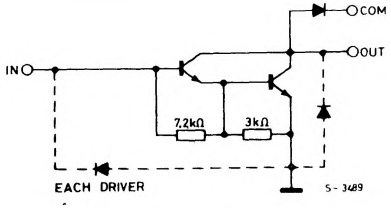
ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_o	Output Voltage	50	V
V_{in}	Input Voltage (for ULN2002A/D - 2003A/D - 2004A/D)	30	V
I_c	Continuous Collector Current	500	mA
I_b	Continuous Base Current	25	mA
T_{amb}	Operating Ambient Temperature Range	– 20 to 85	°C
T_{stg}	Storage Temperature Range	– 55 to 150	°C
T_j	Junction Temperature	150	°C

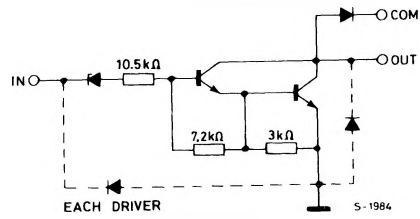
PIN CONNECTION



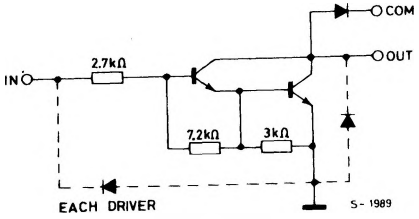
SCHEMATIC DIAGRAM



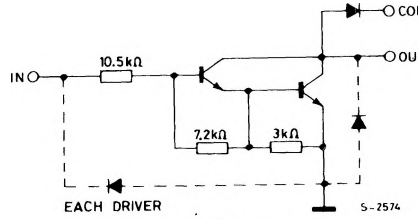
Series ULN-2001A
(each driver)



Series ULN-2002A
(each driver)



Series ULN-2003A
(each driver)



Series ULN-2004A
(each driver)

THERMAL DATA

			DIP–16	SO–16
$R_{th\ j\text{-}amb}$	Thermal Resistance Junction-ambient	Max.	70 °C/W	165 °C/W

ELECTRICAL CHARACTERISTICS (T_{amb} = 25 °C unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit	Fig.
I_{CEX}	Output Leakage Current	V_{CE} = 50 V			50	µA	1a
		T_{amb} = 70 °C V_{CE} = 50 V			100	µA	1a
		T_{amb} = 70 °C for **ULN2002A**					
		V_{CE} = 50 V V_i = 6 V for **ULN2004A**			500	µA	1b
		V_{CE} = 50 V V_i = 1 V			500	µA	1b
$V_{CE(sat)}$	Collector-emitter Saturation Voltage	I_C = 100 mA I_B = 250 µA		0.9	1.1	V	2
		I_C = 200 mA I_B = 350 µA		1.1	1.3	V	2
		I_C = 350 mA I_B = 500 µA		1.3	1.6	V	2
$I_{i(on)}$	Input Current	for **ULN2002A** V_i = 17 V		0.82	1.25	mA	3
		for **ULN2003A** V_i = 3.85 V		0.93	1.35	mA	3
		for **ULN2004A** V_i = 5 V		0.35	0.5	mA	3
		V_i = 12 V		1	1.45	mA	3
$I_{i(off)}$	Input Current	T_{amb} = 70 °C I_C = 500 µA	50	65		µA	4
$V_{i(on)}$	Input Voltage	for **ULN2002A**					
		V_{CE} = 2 V I_C = 300 mA			13	V	5
		for **ULN2003A**					
		V_{CE} = 2 V I_C = 200 mA			2.4	V	5
		V_{CE} = 2 V I_C = 250 mA			2.7	V	5
		V_{CE} = 2 V I_C = 300 mA			3	V	5
		for **ULN2004A**					
		V_{CE} = 2 V I_C = 125 mA			5	V	5
		V_{CE} = 2 V I_C = 200 mA			6	V	5
		V_{CE} = 2 V I_C = 275 mA			7	V	5
		V_{CE} = 2 V I_C = 350 mA			8	V	5
h_{FE}	DC Forward Current Gain	for **ULN2001A**					
		V_{CE} = 2 V I_C = 350 mA	1000			–	2
C_i	Input Capacitance			15	25	pF	–
t_{PLH}	Turn-on Delay Time	0.5 V_i to 0.5 V_o		0.25	1	µs	–
t_{PHL}	Turn-off Delay Time	0.5 V_i to 0.5 V_o		0.25	1	µs	–
I_R	Clamp Diode Leakage Current	V_R = 50 V			50	µA	6
		T_{amb} = 70 °C V_R = 50 V			100	µA	6
V_F	Clamp Diode Forward Voltage	I_F = 350 mA		1.7	2	V	7

TEST CIRCUITS

Figure 1a.

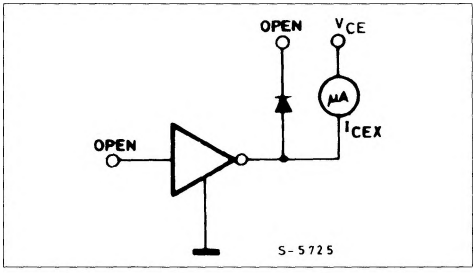


Figure 1b.

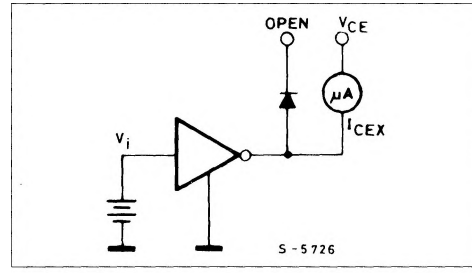


Figure 2.

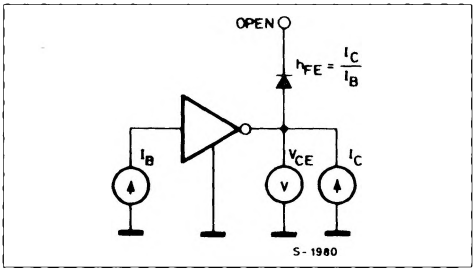


Figure 3.

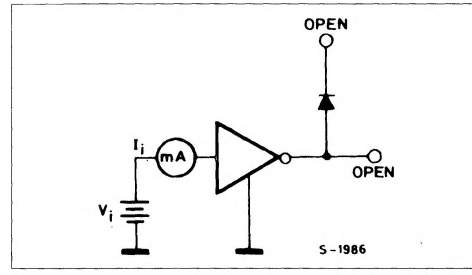


Figure 4.

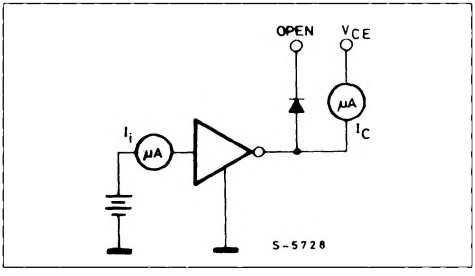


Figure 5.

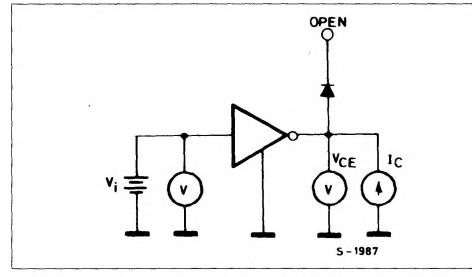


Figure 6.

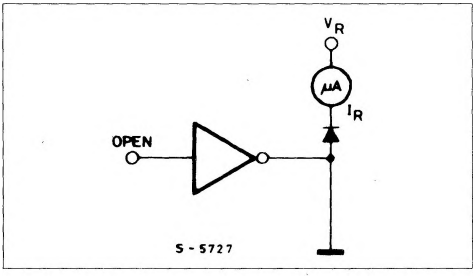
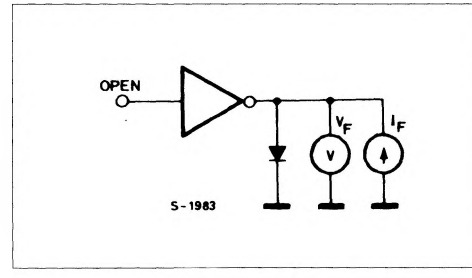



Figure 7.